Unit in mm

Tentative

TOSHIBA Photocoupler GaAs IRED&Photo-triac

TLP260J

Triac Drive
Programmable Controllers
AC-Output Module
Solid State Relay

The TOSHIBA TLP260J is a photocoupler housed in a mini-flat package and consists of a phototriac which is optically coupled to a gallium arsenide infrared-emitting diode.

This type of photocoupler is suitable for use in hybrid ICs as it is thinner and smaller than a 6-pin DIP photocoupler.

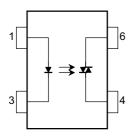
TLP260J: 4-pin mini-flat package (MFSOP6)

Peak OFF-state voltage: 600 V (min)
Trigger LED current: 10 mA (max)
ON-state current: 70 mA (max)

• Isolation voltage: 3000 Vrms (min)

Weight: 0.09 g

Pin Configuration (top view)



- 1: ANODE
- 3: CATHODE
- 4: TERMINAL1
- 6: TERMINAL2

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of Sallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

The products described in this document are subject to the foreign exchange and foreign trade laws.

• The information contained herein is subject to change without notice.

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Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

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Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit	
LED	Forward current		l _F	50	mA	
	Forward current derating (Ta ≥ 5	ΔI _F /°C	-0.7	mA/°C		
	Peak forward current (100 μs pu	I _{FP}	1	Α		
	Reverse voltage	V _R	5	V		
	Junction temperature	Tj	125	°C		
	OFF-state output terminal voltage		V_{DRM}	600	V	
	ON-state RMS current	Ta = 25°C	IT (DMO)	70	- mA	
		Ta = 70°C	I _T (RMS)	40		
ctor	ON-state current derating (Ta ≥ 2	ΔI _T /°C	-0.67	mA/°C		
Detector	Peak ON-state current (100 μs pulse, 120 pps)		I _{TP}	2	А	
	Peak nonrepetitive surge current (P _W = 10 ms, DC = 10%)		I _{TSM}	1.2	А	
	Junction temperature		Tj	100	°C	
Storage temperature range			T _{stg}	-55~125	°C	
Operating temperature range			T _{opr}	-40~100	°C	
Lead soldering temperature (10 s)			T _{sol}	260	°C	
Isolatio	Isolation voltage (AC, 1 min, RH ≤ 60%) (Note1)			3000	Vrms	

Note1: Pins 1 and 3 shorted together, and pins 4 and 6 shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{AC}	_	_	240	V _{ac}
Forward current	l _F	15	20	25	mA
Peak ON-state current	I _{TP}	_	_	1	Α
Operating temperature	T _{opr}	-25	_	85	°C



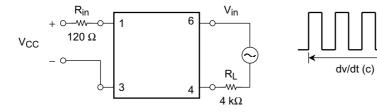
Individual Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
Detector	Peak OFF-state current	I _{DRM}	V _{DRM} = 600 V	_	10	1000	nA
	Peak ON-state voltage	V _{TM}	I _{TM} = 70 mA	_	1.7	2.8	V
	Holding current	lΗ	_	_	1.0	_	mA
	Critical rate of rise of OFF-state voltage	dv/dt	V _{in} = 240 V, Ta = 85°C (Note2)	_	500		V/μs
	Critical rate of rise of commutating voltage	dv/dt (c)	$V_{in} = 60 \text{ Vrms}, I_T = 15 \text{ mA} \text{ (Note2)}$	_	0.2	_	V/μs

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	V _T = 6 V	_	_	10	mA
Capacitance input to output	Cs	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, RH ≤ 60%	5 × 10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC, 1 min.	3000	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	
		DC, 1 min., in oil	_	5000	_	Vdc
Turn-on time	t _{ON}	$V_D = 6 \rightarrow 4 \text{ V}, R_L = 100 \Omega,$ $I_F = \text{Rated } I_{FT} \times 1.5$	_	30	100	μs

Note2: dv/dt test circuit



5 V, V_{CC}